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Preuss E.	Preuss E.	A 41/2, 137-143 (1986)	68.20
Qin L.J.	Wang Z.G.	B 41/2, 125-129 (1986)	33.00
Rabczuk G.	Stanco J.	B 41/4, 245-250 (1986)	42.55
Renieri A.	Coisson R.	B 41/4, 231-234 (1986)	42.60
Rhodin T.	Kasowski R.V.	A 41/1, 61-73 (1986)	68.20
Rieder K.H.	Baumberger M.	A 41/2, 151-156 (1986)	82.65
Rietto G.	Bava E.	B 41/3, 187-195 (1986)	32.80
Ringhofer K.H.	Kukhtarev N.V.	B 41/4, 259-263 (1986)	42.40
Rozkwitalski Z.	Stanco J.	B 41/4, 245-250 (1986)	42.55
Rupp R.A.	Rupp R.A.	B 41/3, 153-168 (1986)	42.30
Ryssel H.	Ryssel H.	A 41/3, 201-207 (1986)	34.00
Sakai T.	Takana H.	A 41/4, 313-316 (1986)	73.40
Sawyer W.D.	Weber J.	A 41/3, 175-178 (1986)	78.55
Schätzel K.	Schätzel K.	B 41/2, 95-102 (1986)	07.65
Schellenberg F.M.	Ortiz C.	B 41/3, 197-203 (1986)	61.80
Schepper P.de	Symons J.	A 41/4, 293-297 (1986)	61.40
Schönhense G.	Schönhense G.	A 41/1, 39-60 (1986)	32.80
Schröter L.	Schröter L.	A 41/1, 95-97 (1986)	33.20
Schulz M.	Will N.F.	A 41/2, 107-114 (1986)	71.55
Schwendemann B.	Hirscher M.	A 41/3, 191-195 (1986)	72.15
Semenets T.I.	Kukhtarev N.V.	B 41/4, 259-263 (1986)	42.40
Sesselmann W.	Sesselmann W.	A 41/3, 209-221 (1986)	79.20
Shimbo M.	Takana H.	A 41/4, 313-316 (1986)	73.40
Shimizu I.	Shirai H.	A 41/4, 261-267 (1986)	61.40
Shirai H.	Shirai H.	A 41/4, 259-265 (1986)	61.40
Shuker R.	Golub I.	B 41/1, 39-41 (1986)	42.65
Singh M.	Weber J.	A 41/3, 175-178 (1986)	78.55
Sliwinski G.	Stanco J.	B 41/4, 245-250 (1986)	42.55
Smirnov V.A.	Belyayev M.V.	B 41/2, 131-133 (1986)	42.65
Stanco J.	Stanco J.	B 41/4, 245-250 (1986)	42.55
Stocker W.	Baumberger M.	A 41/2, 151-156 (1986)	82.65
Stuke M.	Larciprete R.	B 41/4, 213-215 (1986)	82.50
Swanson L.W.	Swanson L.W.	A 41/3, 223-232 (1986)	79.70
Swanson L.W.	Bell A.E.	A 41/4, 337-348 (1986)	79.70
Swanson L.W.	Kingham D.R.	A 41/2, 157-169 (1986)	79.70
Symons J.	Symons J.	A 41/4, 291-295 (1986)	61.40
Takagi Y.	Kojima H.	B 41/1, 43-48 (1986)	33.00
Takahashi M.	Takahashi M.	B 41/2, 91-94 (1986)	33.80
Takami M.	Takahashi M.	B 41/2, 91-94 (1986)	33.80
Takana H.	Takana H.	A 41/4, 311-314 (1986)	73.40
Tanabe A.	Shirai H.	A 41/4, 261-267 (1986)	61.40
Tashiro H.	Takahashi M.	B 41/2, 91-94 (1986)	33.80
Taubmann G.	Taubmann G.	B 41/3, 179-181 (1986)	33.00
Taylor J.R.	French P.M.W.	B 41/1, 53-55 (1986)	42.5M
Taylor J.R.	Gomes A.S.L.	B 41/4, 235-240 (1986)	42.10
Taylor R.S.	Taylor R.S.	B 41/1, 1-24 (1986)	42.5G
Thörner G.	Thörner G.	A 41/1, 99-101 (1986)	73.20
Tomberger G.	Kukhtarev N.V.	B 41/4, 259-263 (1986)	42.40
Tsai M.-H.	Kasowski R.V.	A 41/1, 61-73 (1986)	68.20
Uchida K.	Kojima H.	B 41/1, 43-48 (1986)	33.00
Usmanov T.	Ganeev R.A.	B 41/1, 69-71 (1986)	42.65
Wagniere G.	Wagniere G.	B 41/3, 169-172 (1986)	31.20
Wallenstein R.	Hilbig R.	B 41/4, 225-230 (1986)	42.65
Wang Z.G.	Wang Z.G.	B 41/2, 125-129 (1986)	33.00
Watanabe M.	Watanabe M.	B 41/1, 49-52 (1986)	42.5G
Watanabe S.	Watanabe M.	B 41/1, 49-52 (1986)	42.5G
Weber J.	Weber J.	A 41/3, 175-178 (1986)	78.55
Wertheim G.K.	Wertheim G.K.	A 41/1, 75-81 (1986)	79.60
Whittaker E.A.	Ortiz C.	B 41/3, 197-203 (1986)	61.80
Will N.F.	Will N.F.	A 41/2, 107-114 (1986)	71.55
Witt J.	Witt J.	A 41/1, 103-106 (1986)	61.16
Wolfgarten G.	Pollmann J.	A 41/1, 21-38 (1986)	73.20
Yamada T.	Ohima S.	A 41/4, 287-291 (1986)	61.40
Yamano M.	Ohima S.	A 41/4, 287-291 (1986)	61.40
Yamazaki T.	Takana H.	A 41/4, 313-316 (1986)	73.40
Zacharias H.	Schröter L.	A 41/1, 95-97 (1986)	33.20
Zaremba R.	Stanco J.	B 41/4, 245-250 (1986)	42.55
Zhang Cunhao	He Chun	B 41/4, 251-257 (1986)	34.50
Zhang K.C.	Wang Z.G.	B 41/2, 125-129 (1986)	33.00
Zheng C.-E.	Zheng C.-E.	B 41/1, 31-37 (1986)	34.80